NSN 5961-01-129-7532

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-129-7532 **Inclosure Material:** Metal **Overall Length:** 0.450 inches **End Application:** 7025-01-119-3097 **Mounting Facility Quantity: Mounting Method:** Threaded stud and unthreaded hole **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 0.687 inches **Thread Size:** 0.250 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 100.0 repetitive peak reverse voltage, peak total value and 70.0 reverse voltage, total rms and 1.3 forward voltage, peak **Current Rating Per Characteristic:** 500.00 amperes forward current, average preset and 7.00 milliamperes forward current, average minor **Maximum Operating Tempurature Per Measurement Point:** 180.0 degrees celsius junction **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 tab, solder lug and 1 threaded stud Shelf Life: N/a **Unit Of Measure: Demilitarization:** No